



175°C P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	І р Т _С = +25°С		
-40V	11mΩ @ V _{GS} = -10V	-45A		
	15mΩ @ V _{GS} = -4.5V	-40A		

Description and Applications

This MOSFET has been designed to meet the stringent requirements of automotive applications. It is gualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse polarity protections
- Motor controls
- Power managements

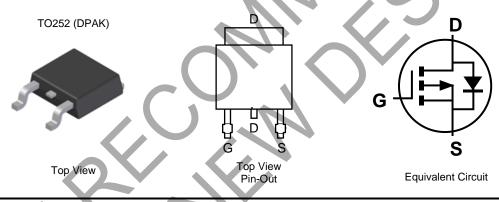
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) The DIODES™ DMPH4015SK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3 Weight: 0.33 grams (Approximate)



Ordering Information (Note 4)

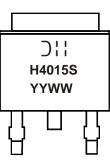
Part Number	Baakaga	Packing		
Fait Number	Package	Qty.	Carrier	
DMPH4015SK3Q-13	TO252 (DPAK)	2,500	Tape & Reel	

. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. . See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Notes: Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃!! = Manufacturer's Marking H4015S = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 22 = 2022) WW = Week (01 to 53)



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	-40	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	Tc = +25°C Tc = +100°C	ID	-45 -35	А
	Steady State	T _A = +25°C T _A = +100°C	ID	-14 -10	А
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	-100	А
Maximum Body Diode Forward Current (Note 6)			ls	-45	А
Avalanche Current, L = 1mH (Note 7)			I _{AS}	-22	А
Avalanche Energy, L = 1mH (Note 7)			Eas	260	mJ

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R ₀ JA	73	°C/W
Total Power Dissipation (Note 6)		PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	38	°C/W
Thermal Resistance, Junction to Case		Rejc	1.0	-C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

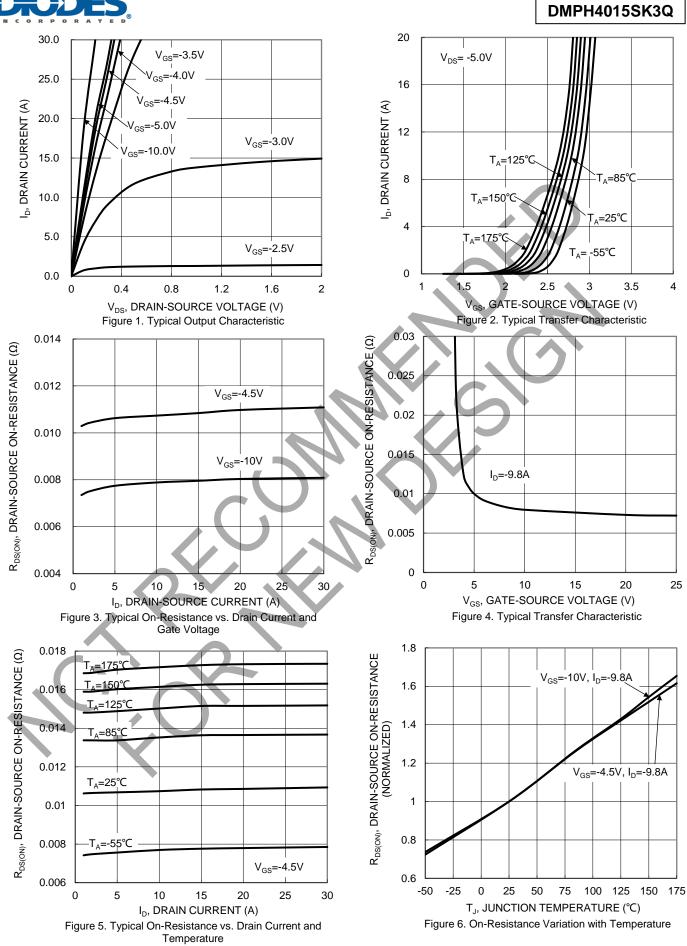
Characteristic	Cymahal	Min	Tura	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Symbol	MUI	Тур	wax	Unit	Test Condition
Drain-Source Breakdown Voltage	BVDSS	-40	_		V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	7_		±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	1633			2100	10 (163 - ±201, 103 - 01
Gate Threshold Voltage	VGS(TH)	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Olatia Decis Oceana Oceana			8	11		V _{GS} = -10V, I _D = -9.8A
Static Drain-Source On-Resistance	RDS(ON)		11	15	mΩ	$V_{GS} = -4.5V, I_D = -9.8A$
Diode Forward Voltage	Vsd		-0.7	-1	V	V _G s = 0V, Is = -1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	I	4234	_		
Output Capacitance	Coss	_	1036	_	pF	V _{DS} = -20V, V _{GS} = 0V f = 1MHz
Reverse Transfer Capacitance	Crss	_	526	_		
Gate Resistance	Rg	_	7.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	42.7	_		
Total Gate Charge (V _{GS} = -10V)	Qg		91	_	nC	$V_{DS} = -20V,$
Gate-Source Charge	Qgs	_	14.2	_	nC	I _D = -9.8A
Gate-Drain Charge	Qgd		13.5	_		
Turn-On Delay Time	tD(ON)		13.2	_		
Turn-On Rise Time	t _R		10	_		$V_{GS} = -10V$, $V_{DD} = -20V$, $R_G = 6\Omega$, $I_D = -1A$
Turn-Off Delay Time	tD(OFF)	_	303		ns	
Turn-Off Fall Time	tF	_	138			
Reverse Recovery Time	t _{RR}		26	_	ns	I _F = -9.8A, di/dt = -100A/µs
Reverse Recovery Charge	Qrr	_	20	_	nC	IF = -9.8A, di/dt = -100A/µs

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. Notes:

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.

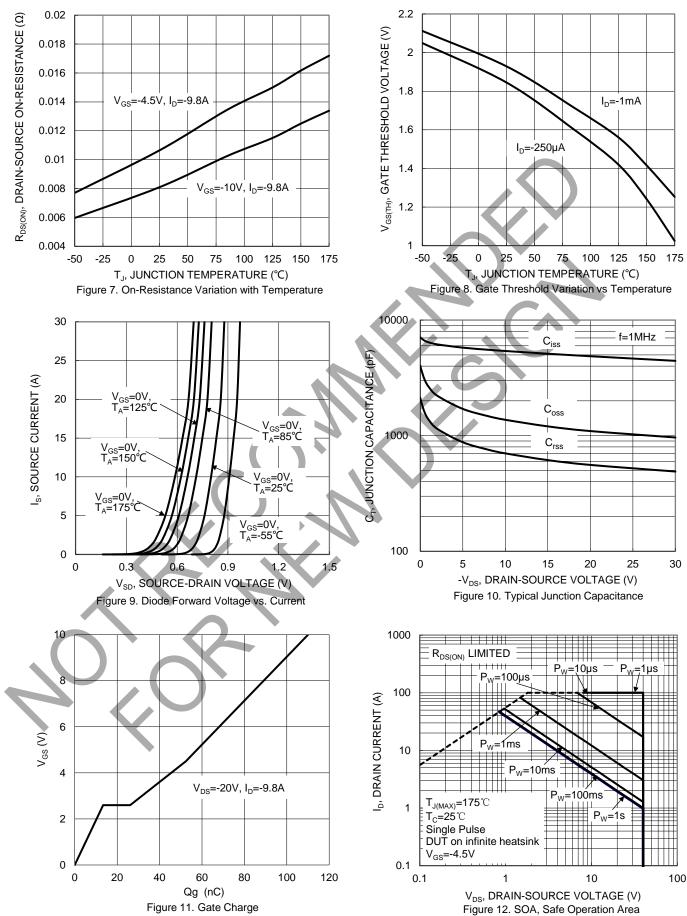




DMPH4015SK3Q Document number: DS38125 Rev. 5 - 3



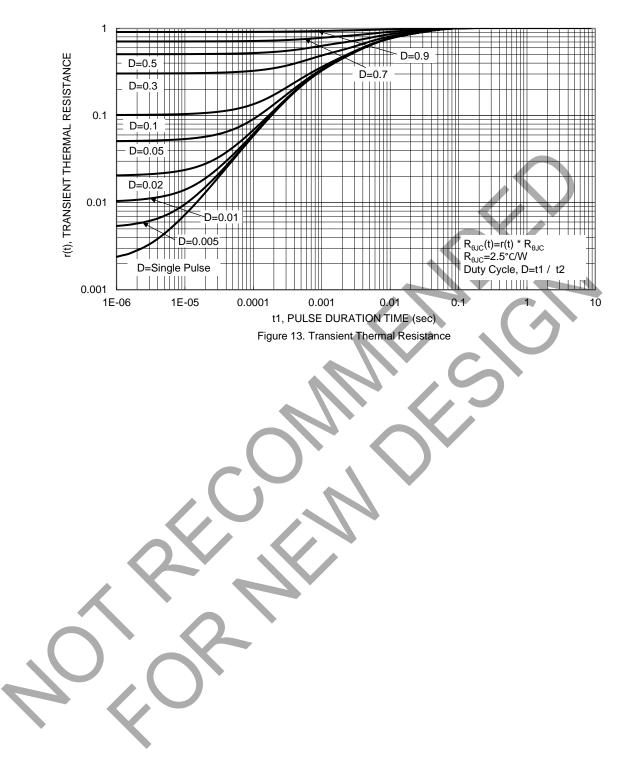
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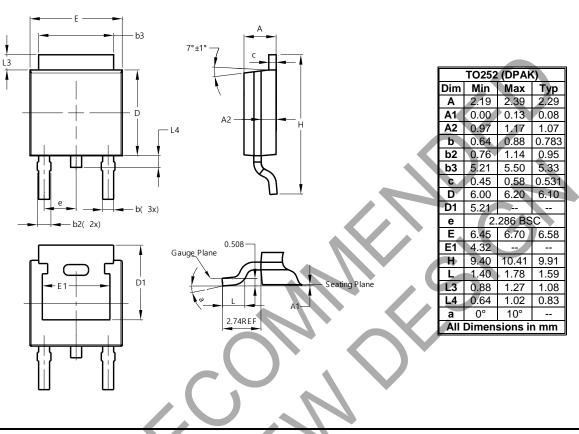






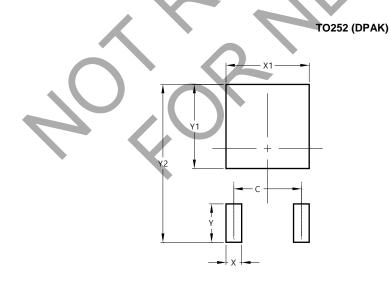
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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